

### Solid State Devices, Inc.

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## **Designer's Data Sheet**

Part Number/Ordering Information 1/

1N70

L Screening 2/
= Not Screened
TX = TX Level
TXV = TXV
S = S Level

Package Type

= Axial Leaded SMS = Surface Mount Square Tab

Voltage/Family

66= 50V

67 = 100V

68 = 150V

# 1N7066 thru 1N7068 and 1N7066SMS thru 1N7068SMS

10 AMP 50 - 150 VOLTS 30 ns HYPERFAST RECOVERY RECTIFIER

#### **FEATURES:**

- Hyper Fast Reverse Recovery: 30ns Maximum<sup>4/</sup>
- High Surge Current: 325 A Maximum
- Hermetically Sealed
- Low Forward Voltage Drop .95 @10A
- Void Free Chip Construction
- Solid Silver Leads
- Available in Axial & Square Tab Versions
- TX, TXV, and S-Level Screening Available <sup>2/</sup>
- Axial Lead Higher Current Replacements for: 1N5807, 1N5809, 1N5811
- Possible SMS Replacements for Stud Mount: 1N5812, 1N5814, 1N5816

MAXIMUM RATINGS 3/						
RATING		VALUE	UNIT			
Peak Repetitive Reverse  Voltage And DC Blocking Voltage  1N7068  1N7068	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	50 100 150	Volts			
Average Rectified Forward Current (Axial TL $\leq$ 55°C; SMS TEC $\leq$ 100°C) $\stackrel{5}{\sim}$	Io	10	Amps			
Peak Surge Current (8.3 ms pulse, half sine wave, superimposed on Io, allow junction to reach equilibrium between pulses, T <sub>A</sub> = 25°C)	I <sub>FSM</sub>	325	Amps			
Operating & Storage Temperature	$T_J$ and $T_{STG}$	-65 to +175	°C			
Thermal Resistance  Junction to Lead for Axial, L = .125"  Junction to End Tab for Surface Mount		8 4.5	°C/W			

### **NOTES:**

 $\underline{\textbf{1}}/ \ \ \text{For Ordering Information, Price, Operating Curves, and Availability-Contact Factory}.$ 

2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.

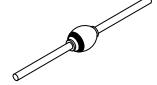
3/ Unless Otherwise Specified, All Electrical Characteristics @25°C.

 $\underline{4}$ /  $I_F = 1A$ ,  $I_R = 1A$ ,  $I_{RR} = 0.1A$ ,  $T_A = 25$ °C

5/ Operating at higher Io currents may be achieved based on specific application and device mounting if Tj is maintained below 175°C.

**Axial Leaded** 

SMS





**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: RC0119C** 

DOC



# 1N7066 thru 1N7068 and 1N7066SMS thru 1N7068SMS

ELECTRICAL CHARACTERISTICS 3/							
CHARACTERISTICS		SYMBOL	VALUE	UNIT			
			MAX				
Instantaneous Forward Voltage Drop	$\begin{split} I_F = 6.0 \; Adc \;, \; T_A = +25 ^{\circ}C, \; 300 \mu s \; pulse \\ I_F = 10 \; Adc \;, \; T_A = 25 ^{\circ}C, \; 300 \mu s \; pulse \\ I_F = 20 \; Adc \;, \; T_A = 25 ^{\circ}C \\ I_F = 6 \; Adc \;, \; T_A = 125 ^{\circ}C \\ I_F = 6 \; Adc \;, \; T_A = -55 ^{\circ}C \end{split}$	$egin{array}{c} V_{F1} \ V_{F2} \ V_{F3} \ V_{F4} \ V_{F5} \ \end{array}$	0.900 0.950 1.020 0.85 1.05	Vdc			
Reverse Leakage Current	Rated $V_R$ , $T_A = +25$ °C, 300 $\mu$ s pulse minimum Rated $V_R$ , $T_A = +100$ °C, 300 $\mu$ s pulse minimum	$I_{R1}$ $I_{R2}$	20 1	μA mA			
Junction Capacitance $V_R = 10 \text{ Vdc}, f = 1 \text{MHz}, T_A = 25^{\circ}\text{C}$		C <sub>J</sub>	80	pF			
Reverse Recovery Time $I_F = 1A$ , $I_R = 1A$ , $I_{RR} = 0.1A$ , $T_A = 25$ °C		$\mathbf{t_{rr}}$	30	ns			

Package Outlines:

	I ACKAGE OUTINES:				
DIMENSIONS (inches)			DIMENSIONS	` '	
DIM.	Minimum	Maximum	DIM.	Minimum	Maximum
A	.135	.165	A	.172	.180
В	.135	.155	В	.180	.220
С	.037	.042	С	.020	.028
D	1.000		D	.002	
AXIAI	D B D	ØC ØA	SMS		- A -

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